

SILICON POWER TRANSISTOR 2SA1847

PNP SILICON EPITAXIAL TRANSISTOR FOR HIGH-SPEED SWITCHING

The 2SA1847 is a power transistor developed for high-speed switching and features a high here at low $V_{CE(sat)}$. This transistor is ideal for use as a driver in DC/DC converters and actuators.

In addition, this transistor features a package that can be auto-mounted in radial taping specifications, thus contributing to mounting cost reduction.

FEATURES

- · Auto-mount possible in radial taping specifications
- · Resin-molded insulation type package with power rating of 1.8 W in stand-alone conditions
- High hFE and low VCE(sat):

 $V_{\text{CE(sat)}} = -0.3$ V MAX. @Ic = -6.0 V, IB = -0.3 A

 $h_{\text{FE}} \geq 100 \qquad \qquad @V_{\text{CE}} = -2.0 \text{ V}, \text{ Ic} = -2.0 \text{ A}$

· Fast switching speed

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Conditions	Ratings	Unit
Collector to base voltage	Vсво		-150	V
Collector to emitter voltage	VCEO		-100	V
Emitter to base voltage	VEBO		-7.0	V
Collector current (DC)	IC(DC)		-10	А
Collector current (pulse)	IC(pulse)	$PW \le 300 \ \mu s$, duty cycle $\le 2\%$	-20	А
Base current (DC)	B(DC)		-6.0	А
Total power dissipation	Рт	Ta = 25°C	1.8	w
Junction temperature	Tj		150	°C
Storage temperature	Tstg		-55 to +150	°C

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ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	$V_{CB} = -100 \text{ V}, \text{ I}_{E} = 0$			-10	μA
Collector cutoff current	ICER	V _{CE} = -100 V, R _{EB} = 50 Ω Ta = 125°C			-1.0	mA
Collector cutoff current	ICEX1	$V_{CE} = -100 \text{ V}, \text{ V}_{BE(off)} = 1.5 \text{ V}$			-10	μA
Collector cutoff current	ICEX2	$V_{CE} = -100 \text{ V}, \text{ V}_{BE(off)} = 1.5 \text{ V}$ $Ta = 125^{\circ}\text{C}$			-1.0	mA
Emitter cutoff current	Іево	$V_{EB} = -5.0 \text{ V}, \text{ Ic} = 0$			-10	μA
DC current gain	hfe1*	Vce = -2.0 V, Ic = -0.5 A	100			_
DC current gain	hFE2*	Vce = -2.0 V, Ic = -2.0 A	100		400	-
DC current gain	hfe3*	Vce = -2.0 V, Ic = -6.0 A	60			_
Collector saturation voltage	VCE(sat)1*	Ic = -6.0 A, Iв = -0.3 A			-0.3	V
Collector saturation voltage	VCE(sat)2*	Ic = -8.0 A, I _B = -0.4 A			-0.5	V
Base saturation voltage	VBE(sat)1*	Ic = -6.0 A, Iв = -0.3 A			-1.2	V
Base saturation voltage	VBE(sat)2*	Ic = -8.0 A, I _B = -0.4 A			-1.5	V
Gain bandwidth product	fт	Vce = -10 V, lc = -0.5 A		150		MHz
Collector capacitance	Cob	Vсв = -10 V, IE = 0, f = 1 MHz		250		pF
Turn-on time	ton	Ic = -6.0 A			0.3	μs
Storage time	tstg	$I_{B1} = -I_{B2} = -0.3 \text{ A}$			1.5	μs
Fall time	tr	R∟ = 8.3 Ω, Vcc = −50 V			0.4	μs

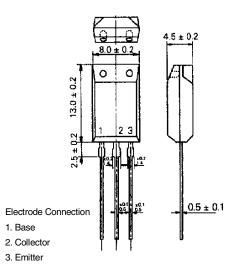
* Pulse test PW \leq 350 μ s, duty cycle \leq 2%

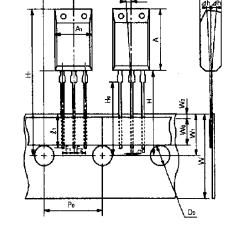
hfe CLASSIFICATION

Marking	М	L	К	
hfe	100 to 200	150 to 300	200 to 400	

PACKAGE DRAWING (UNIT: mm)

TAPING SPECIFICATION



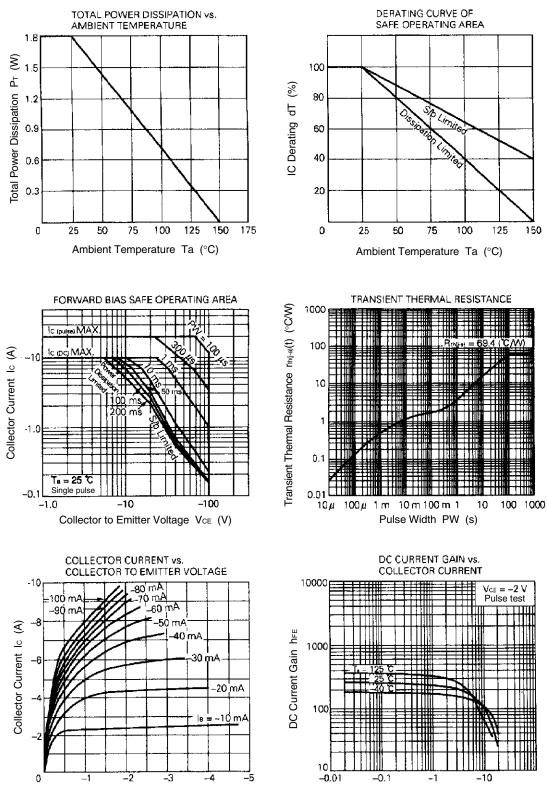


Aı	8.0 ± 0.2
A	13.0 ± 0.2
Do	φ4.0 ± 0.2
d	0.5 ± 0.1
Fi	$2.5^{+0.4}_{-0.1}$
F ₂	$2.5^{+0.4}_{-0.1}$
н	20.0 MAX.
Ho	16.0 ± 0.5
Hi	32.2 MAX.
⊿h	0 ± 1.0
€,	2.5 MIN.
Р	12.7 ± 1.0
P₀	12.7 ± 0.3
P۶	6.35 ± 0.5
⊿P	0 ± 1.3
т	4.5 ± 0.2
W	18.0 ^{+1.0}
W٥	5.0 MIN.
Wi	9.0 ± 0.5
W2	0.7 MIN.

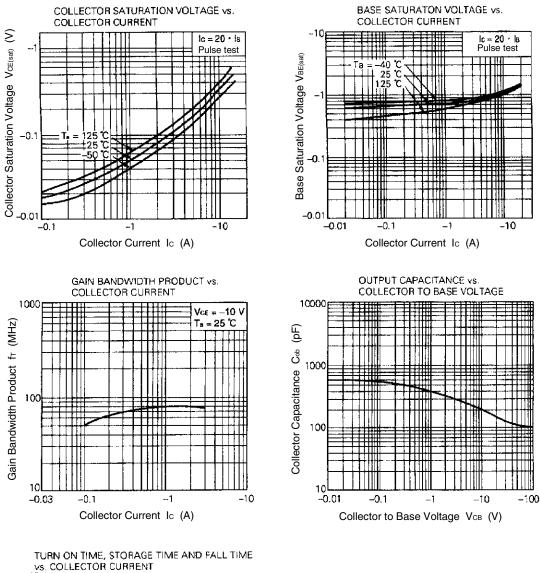
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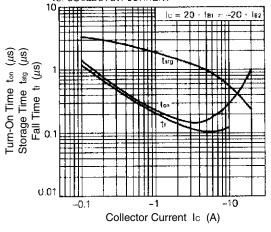
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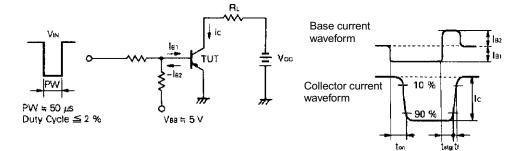


Collector to Emitter Voltage VCE (V)





SWITCHING TIME (ton, tstg, tf) TEST CIRCUIT



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